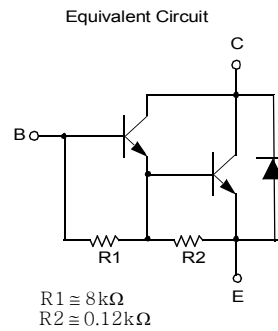
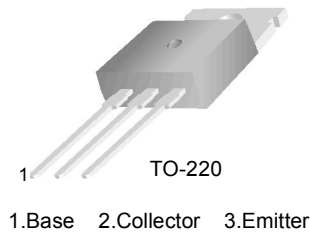


TIP120/TIP121/TIP122

NPN Epitaxial Darlington Transistor

- Medium Power Linear Switching Applications
- Complementary to TIP125/126/127



Absolute Maximum Ratings* $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units	
V_{CBO}	Collector-Base Voltage	: TIP120	60	V
		: TIP121	80	V
		: TIP122	100	V
V_{CEO}	Collector-Emitter Voltage	: TIP120	60	V
		: TIP121	80	V
		: TIP122	100	V
V_{EBO}	Emitter-Base Voltage	5	V	
I_C	Collector Current (DC)	5	A	
I_{CP}	Collector Current (Pulse)	8	A	
I_B	Base Current (DC)	120	mA	
P_C	Collector Dissipation ($T_a=25^\circ\text{C}$)	2	W	
	Collector Dissipation ($T_C=25^\circ\text{C}$)	65	W	
T_J	Junction Temperature	150	$^\circ\text{C}$	
T_{STG}	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$	

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics* $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{\text{CEO(sus)}}$	Collector-Emitter Sustaining Voltage : TIP120 : TIP121 : TIP122	$I_C = 100\text{mA}, I_B = 0$	60 80 100			V V V
I_{CEO}	Collector Cut-off Current : TIP120 : TIP121 : TIP122	$V_{\text{CE}} = 30\text{V}, I_B = 0$ $V_{\text{CE}} = 40\text{V}, I_B = 0$ $V_{\text{CE}} = 50\text{V}, I_B = 0$			0.5 0.5 0.5	mA mA mA
I_{CBO}	Collector Cut-off Current : TIP120 : TIP121 : TIP122	$V_{\text{CB}} = 60\text{V}, I_E = 0$ $V_{\text{CB}} = 80\text{V}, I_E = 0$ $V_{\text{CB}} = 100\text{V}, I_E = 0$			0.2 0.2 0.2	mA mA mA
I_{EBO}	Emitter Cut-off Current	$V_{\text{BE}} = 5\text{V}, I_C = 0$			2	mA
h_{FE}	* DC Current Gain	$V_{\text{CE}} = 3\text{V}, I_C = 0.5\text{A}$ $V_{\text{CE}} = 3\text{V}, I_C = 3\text{A}$	1000 1000			
$V_{\text{CE(sat)}}$	* Collector-Emitter Saturation Voltage	$I_C = 3\text{A}, I_B = 12\text{mA}$ $I_C = 5\text{A}, I_B = 20\text{mA}$			2.0 4.0	V V
$V_{\text{BE(on)}}$	* Base-Emitter On Voltage	$V_{\text{CE}} = 3\text{V}, I_C = 3\text{A}$			2.5	V
C_{ob}	Output Capacitance	$V_{\text{CB}} = 10\text{V}, I_E = 0, f = 0.1\text{MHz}$			200	pF

* Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%

Typical characteristics

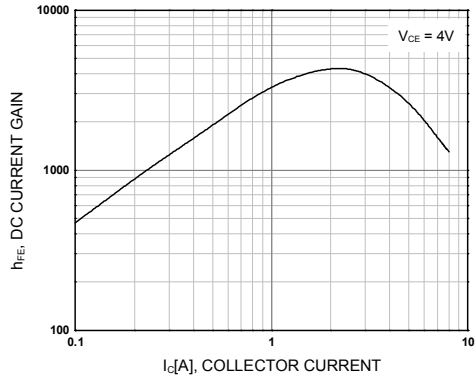


Figure 1. DC current Gain

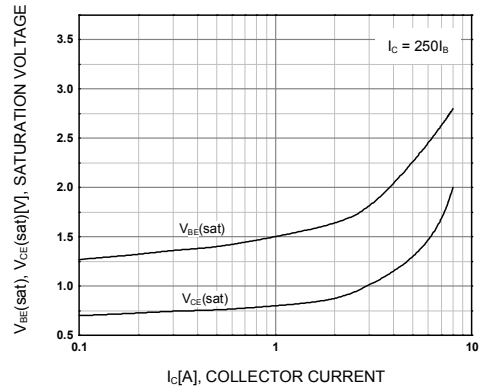


Figure 2. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

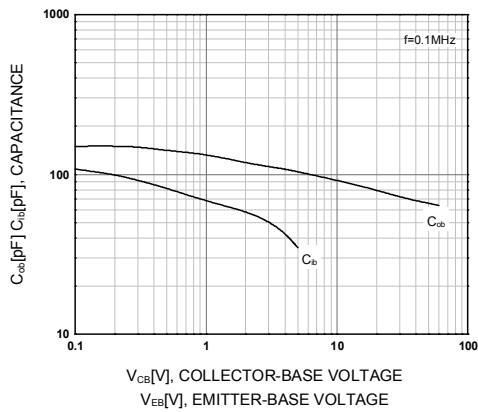


Figure 3. Output and Input Capacitance
vs. Reverse Voltage

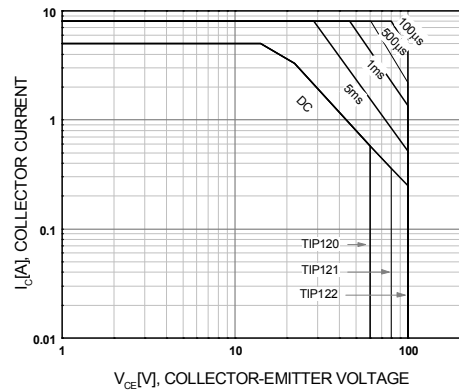


Figure 4. Safe Operating Area

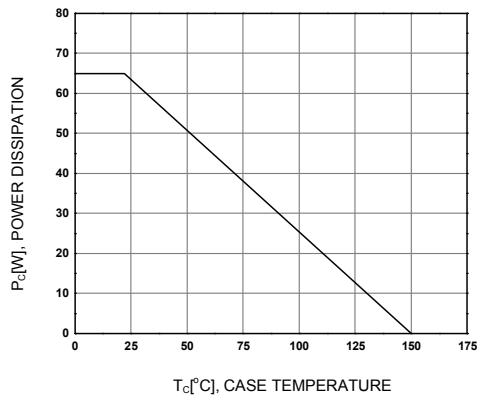
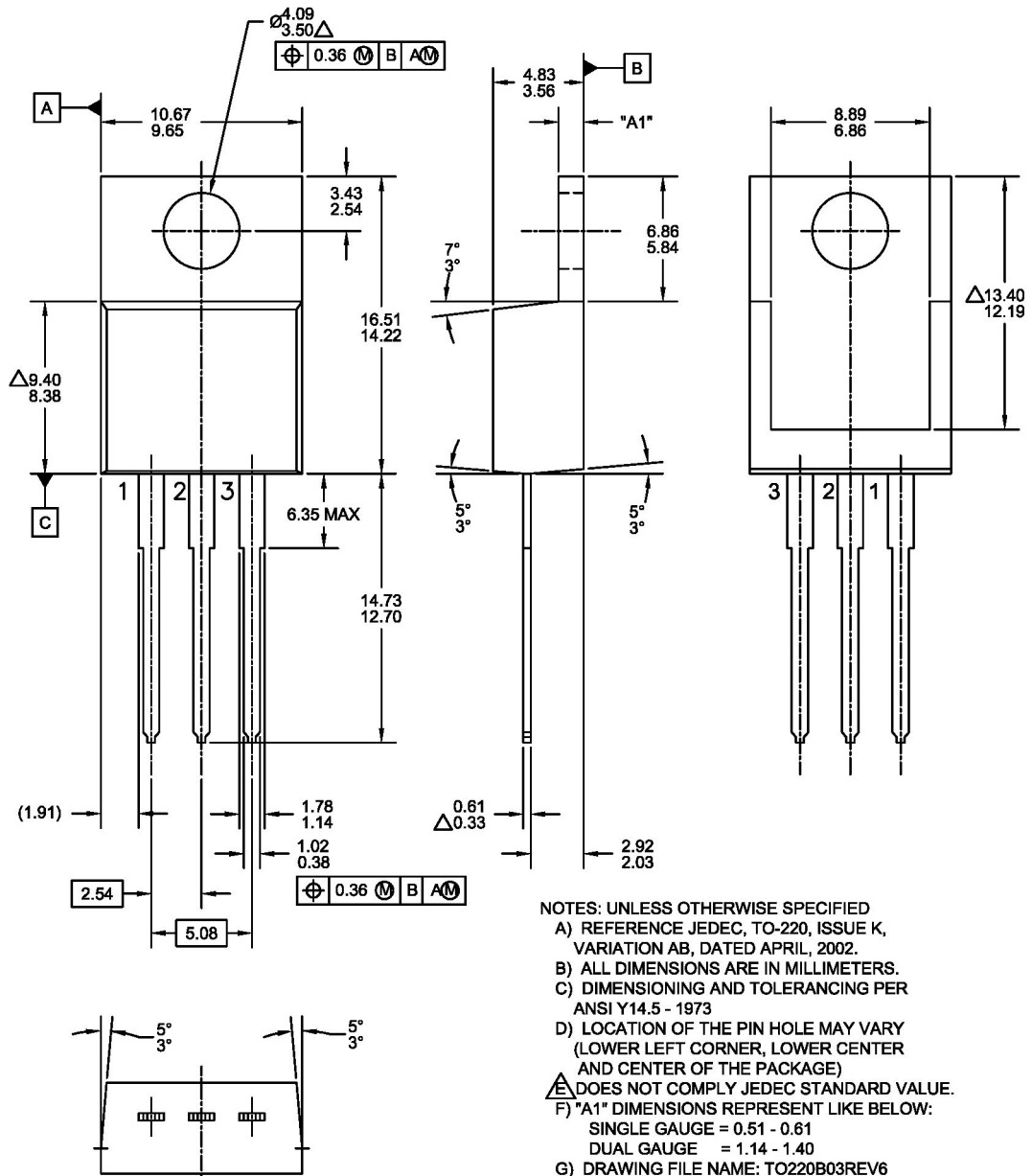


Figure 5. Power Derating

Mechanical Dimensions

TO220





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